



0.45 Ω , Low Voltage Dual SPDT Analog Switch with Negative Swing Audio Capability

DESCRIPTION

The DG2750 is a dual SPDT low on-resistance switch designed to from a single 1.6 V to 5.5 V power supply. It is a bi-directional switch, and is capable of switching negative swing audio without the need for a coupling capacitor. With a single power supply, the audio signal can swing over the range from ((V+) - 5) to V+.

Guaranteed to operate with 1.4 V logic when V+ is in the range of 2.7 V to 5.5 V, the DG2750 will allow an easy interface with low voltage DSP or ASIC control logic.

The DG2750 is built on sub micron CMOS low voltage process technology, has very low quiescent current, and provides greater than 600 mA latch-up protection, as tested per JESD78.

The DG2750 is assembled in compact mQFN10, $1.4 \text{ mm} \times 1.8 \text{ mm} \times 0.55 \text{ mm}$ and ultra thin UTMQFN of 0.35 mm thickness.

As a committed partner to the community and the environment, Vishay Siliconix manufactures this product with lead (Pb)-free device termination. The miniQFN-10 package has a nickel-palladium-gold device termination and is represented by the lead (Pb)-free "-E4" suffix to the ordering part number. The nickel-palladium-gold device terminations meet all JEDEC® standards for reflow and MSL rating.

As a further sign of Vishay Siliconix's commitment, the DG2750 is fully RoHS-complaint and halogen-free.

FEATURES

- 1.6 V to 5.5 V single power rail operation
- Capable to switch negative swing audio without DC blocking capacitor

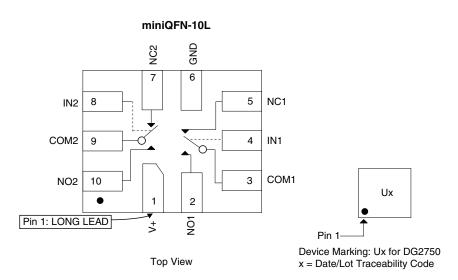


- Low signal distortion: THD+N < -98 dB
- · Low on-resistance
- 1.4 V high logic
- Latch-up current > 600 mA (JESD78)
- ESD (HBM): 8 kV
- Reduced power consumption
- Reduce board space
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- Cellular phones
- · Portable media players
- · Computer and game machine
- Handheld healthcare and instruments

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION





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ORDERING INFORMATION						
PART NUMBER	TEMPERATURE RANGE	PACKAGE	SIZE			
DG2750DN-T1-E4	-40 °C to +85 °C	miniQFN-10	1.4 mm x 1.8 mm x 0.55 mm			
DG2750DN1-T1-GE4	-40 C to +65 C	UTMQFN-10	1.4 mm x 1.8 mm x 0.35 mm			

TRUTH TABLE, DG2750						
IN1 (PIN 4)	IN2 (PIN 8)	FUNCTION				
0	X	COM1 = NC1				
1	X	COM1 = NO1				
Х	0	COM2 = NC2				
Х	1	COM2 = NO2				

ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C, unless otherwise noted)						
PARAMETER		LIMIT	UNIT			
Reference to GND	V+, IN	-0.3 to +6	V			
neletefice to GND	COM, NO, NC a	(V+) -5.5 or -2.5 whichever higher, (V+ + 0.3)				
Current (Any Terminal except COM, NO, NC, IN)		30				
Continuous Current (COM, NO, NC, IN)		± 250	mA			
Peak Current (Pulsed at 1 ms, 10 % Duty Cycle)		± 500				
Storage Temperature (D Suffix)		-65 to +150	°C			
Power Dissipation (Packages) b	miniQFN-10 ^c	208	mW			
ESD (Human Body Model) I/O to GND		8	kV			
Latch-up (per JESD78)		600	mA			

Notes

- a. Signals on COM, NO, NC, exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings
- b. All leads welded or soldered to PC board
- c. Derate 2.6 mW/°C above 70 °C

SPECIFICATIONS (V+ = 2.7 V , $\pm 10 \%$)								
PARAMETER	SYMBOL OT	TEST CONDITIONS	TEMP. a	LIMITS -40 °C to +85 °C			UNIT	
		OTHERWISE UNLESS SPECIFIED		MIN.b	TYP. c	MAX. b	1	
Analog Switch								
Analog Signal Range ^d	V_{ANALOG}		Full	-2.5	-	V+	V	
On-Resistance	R _{DS(on)}		Room	-	0.45	1		
On-Resistance		V+ = 2.7 V,	Full	=	-	1.3		
On-Resistance Match	ΔR_{ON}	$V_S = ((V+) -4.5 \text{ V}, -1 \text{ V}, 0 \text{ V}, 1 \text{ V}, 2 \text{ V}, V+),$ $I_S = 100 \text{ mA}$	Room	-	0.1	-	Ω	
On-Resistance Flatness	R _{ON} Flatness	0	Room	-	0.3	-		
Switch Off Lankage Comment	I _{NO/NC(off)}		Room	=	50	-		
Switch Off Leakage Current	V + 2.7 V	V+ = 2.7 V,	Full	-250	-	250	nA	
Channel On Leakers Comment		$V_{NC/NO}$ = -2.5 V or 2.5 V, V_{COM} = 2.5 V or -2.5 V	Room	-	50	-	ΠA	
Channel On Leakage Current	Channel On Leakage Current I _{COM(on)} V _{COM} = 2.3 V or -2.3		Full	-250	-	250		
Digital Control								
Input Voltage High	V _{INH}	V. 07V+-40V	Full	1.4	-	-		
Input Voltage Low	V _{INL}	V+ = 2.7 V to 4.3 V	Full	-	-	0.6	V	
Input Capacitance	C _{IN}		Room	-	6.5	-	pF	
Input Current	I _{INL} or I _{INH}	$V_{IN} = 0$ or V+	Full	-1	-	1	μΑ	

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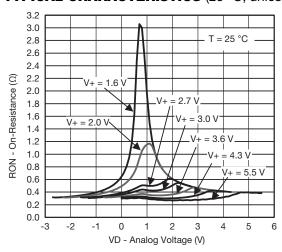
SPECIFICATIONS (V+ = 2.7 V , $\pm 10 \text{ \%}$)								
PARAMETER	SYMBOL	TEST CONDITIONS OTHERWISE UNLESS SPECIFIED	TEMP. a	LIMITS -40 °C to +85 °C			UNIT	
		OTHERWISE UNLESS SPECIFIED		MIN.b	TYP. c	MAX. b		
Dynamic Characteristics								
Break-Before-Make Time e, d	t _{BBM}		Room	800	1160	-		
Break-Belore-Wake Time	чВВМ		Full	1000	-	-	ns	
Enable Turn-On Time ^{e, d}	+	V+ = 3 V, V_S = 1.5 V, R_L = 50 $Ω$, C_L = 35 pF	Room	-	1200	2100		
Litable fulli-Off fillie 3, 2	t _{ON(EN)}		Full	-	-	2500	115	
Enable Turn-Off Time ^{e, d}	+		Room	-	33	130		
Enable furn-On Time 9, 9	t _{OFF(EN)}		Full	-	-	150		
Charge Injection ^d	Q _{INJ}	C_L = 1 nF, R_{GEN} = 0 Ω , V_{GEN} = 0 V		-	4	-	рС	
Total Harmonic Distortion Plus Noise ^d	THD+N	f = 20 Hz to 20 kHz, V_{COM} = 0.5 V_{P-P} , R_S = R_L = 600 Ω ; DC bias = 0 V		-	< -98	-	dB	
Off-Isolation ^d	OIRR	$V+ = 3 V, R_L = 50 \Omega, C_L = 5 pF,$		-	-54	-	dB	
Crosstalk d, f	X _{TALK}	f = 300 kHz	Room	-	-60	-		
Bandwidth ^d	BW	$V+ = 3 V, R_L = 50 \Omega, -3 dB$		=	49	=.	MHz	
Channel-Off Capacitance d	C _{NC/NO(off)}	V+ = 3 V. f = 1 MHz		-	36	-	~F	
Channel-On Capacitance d	C _{COM/NC/NO(on)}	V+ = 3 V, I = I MIHZ		-	106	-	pF	
Power Supply								
Power Supply Range	V+			1.6	=	5.5	V	
Power Supply Current	I+	$V_{IN} = 0 \text{ V, or V+}$	Full	-	-	2	μΑ	

Notes

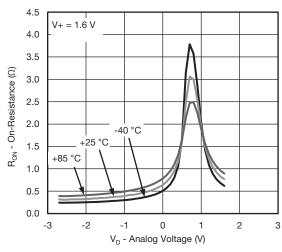
- a. Room = 25 °C, Full = as determined by the operating suffix
- b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet
- c. Typical values are for design aid only, not guaranteed nor subject to production testing
- d. Guarantee by design, not subjected to production test
- e. $V_{IN} = V + voltage$ to perform proper function
- f. Crosstalk measured between channels

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



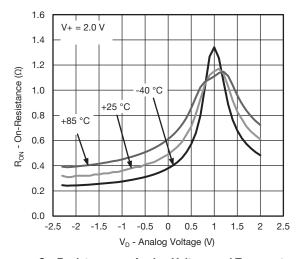




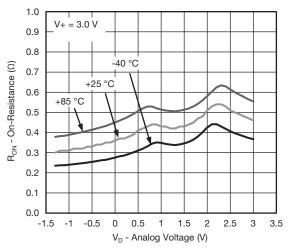
On-Resistance vs. Analog Voltage and Temperature



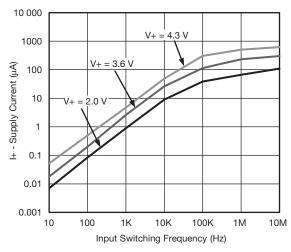
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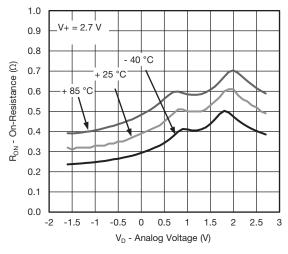
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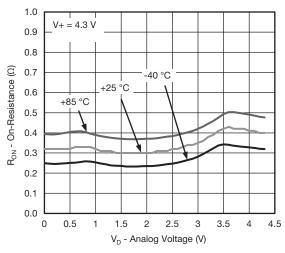
On-Resistance vs. Analog Voltage and Temperature



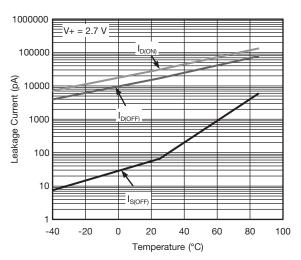
Supply Current vs. Input Switching Frequency



On-Resistance vs. Analog Voltage and Temperature



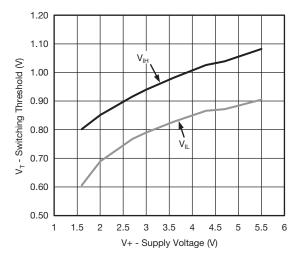
On-Resistance vs. Analog Voltage and Temperature



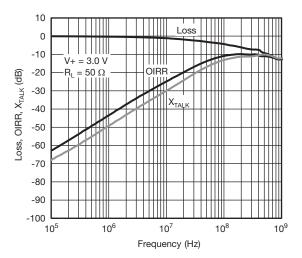
Leakage Current vs. Temperature



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

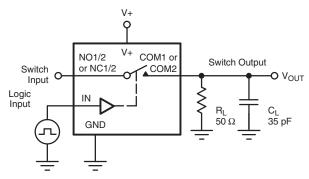


Switching Threshold vs. Supply Voltage



Insertion Loss, Off-Isolation, Crosstalk vs. Frequency

TEST CIRCUITS



C_L (includes fixture and stray capacitance)

$$V_{OUT} = V_{COM} \left(\frac{R_L}{R_L + R_{ON}} \right)$$

Logic Input V_{INH} V_{INL} $t_r < 5 \text{ ns}$ $t_f < 5 \text{ ns}$

Logic "1" = Switch on Logic input waveforms inverted for switches that have the opposite logic sense.

Fig. 1 - Switching Time

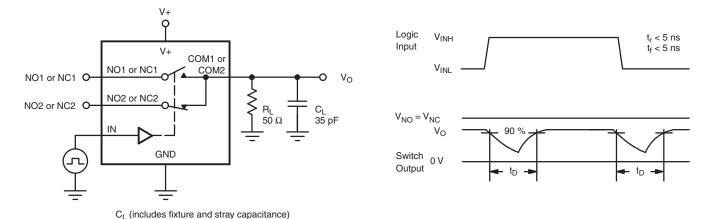
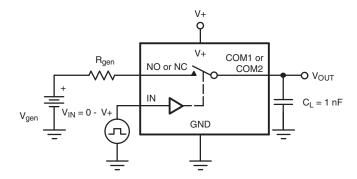
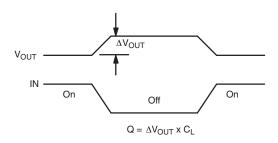


Fig. 2 - Break-Before-Make Interval



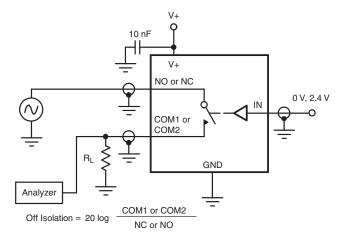
TEST CIRCUITS





IN depends on switch configuration: input polarity determined by sense of switch.

Fig. 3 - Charge Injection





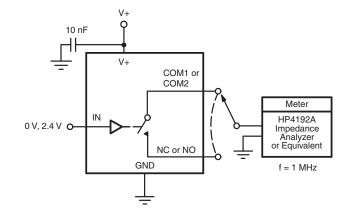
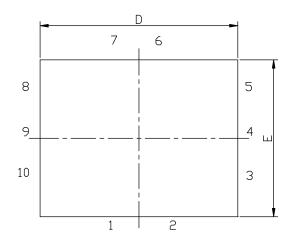


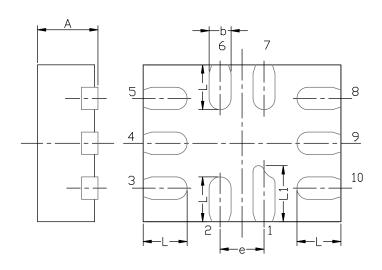
Fig. 5 - Channel Off/On Capacitance

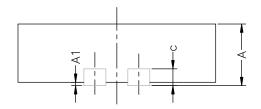
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MINI QFN-10L CASE OUTLINE







DIM		MILLIMETERS			INCHES			
	MIN.	NAM.	MAX.	MIN.	NAM.	MAX.		
А	0.45	0.55	0.60	0.0177	0.0217	0.0236		
A1	0.00	-	0.05	0.000	-	0.002		
b	0.15	0.20	0.25	0.006	0.008	0.010		
С		0.150 or 0.127 REF ⁽¹⁾			0.006 or 0.005 REF ⁽¹⁾			
D	1.70	1.80	1.90	0.067	0.071	0.075		
E	1.30	1.40	1.50	0.051	0.055	0.059		
е		0.40 BSC			0.016 BSC			
L	0.35	0.40	0.45	0.014	0.016	0.018		
L1	0.45	0.50	0.55	0.0177	0.0197	0.0217		

Note

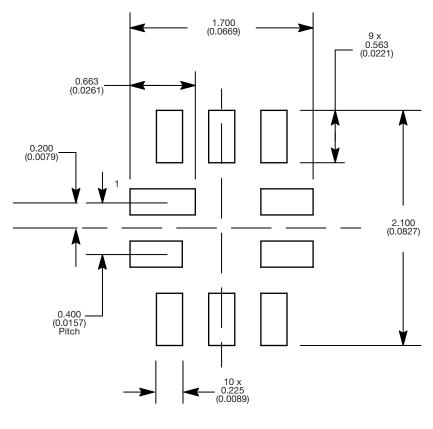
 $^{(1)}$ The dimension depends on the leadframe that assembly house used.

ECN T16-0163-Rev. B, 16-May-16 DWG: 5957



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RECOMMENDED MINIMUM PADS FOR MINI QFN 10L



Mounting Footprint Dimensions in mm (inch)



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